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February 2008

# 74LVT2244, 74LVTH2244 Low Voltage Octal Buffer/Line Driver with 3-STATE Outputs and 25 $\Omega$ Series Resistors in the Outputs

#### **Features**

- Input and output interface capability to systems at 5V V<sub>CC</sub>
- Equivalent 25Ω-Series resistors on outputs
- Bushold data inputs eliminate the need for external pull-up resistors to hold unused inputs (74LVTH2244), also available without bushold feature (74LVT2244)
- Live insertion/extraction permitted
- Power Up/Down high impedance provides glitch-free bus loading
- Outputs source/sink -12mA/+12mA
- Latch-up performance exceeds 500mA
- ESD performance:
  - Human-body model > 2000V
  - Machine model > 200V
  - Charged-device model > 10( V

## **General Description**

The LVT2244 and LVTH2244 ar octa. uffers and line drivers designed to be emrloy, as monory address drivers, clock drivers are ous or interest ansmitters or receivers which provide in loved a board density. The equivalent 25s. Perior resistres helps reduce output overshoot are under a pot.

The LVTr 244 ata ir uts include bushold, eliminating the ad to exto pull-up resistors to hold unused but

The collabuffers and line drives are designed for low-voltage (3.3V) V<sub>CC</sub> applications, but with the capability to provide a The interface to a 5V environment. The LVT2244 and LVTH2244 are liabricated with an advanced BiCMCS technology to achieve high speed operation similar to 5V ABT while maintaining low power dissipation.

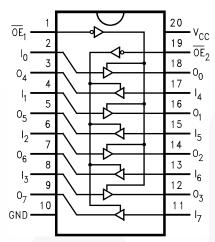
## Ordering I format.

| N. 1b.          | Packag :<br>Number | Package Description  |
|-----------------|--------------------|--|
| LVT22 WI        | M20B               | 20-Lead Smal Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide    |
| 74. T2° 4SJ     | M20D               | 20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide                |
| 74LV , 2244MT C | ATC20              | 20-1 ead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide |
| 74LVTF 2244WM   | M.20B              | 20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide   |
| 74LVTH2244SJ    | M20D               | 20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide                |
| 74LVTH2244MTC   | MTC20              | 20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide  |

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering number.

All packages are lead free per JEDEC: J-STD-020B standard.

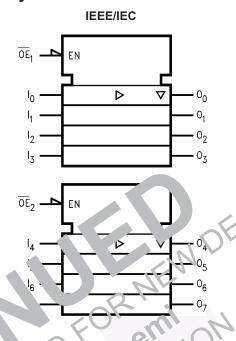
## **Connection Diagram**



## **Pin Description**

| Pin Names                             | Description                  |
|---------------------------------------|------------------------------|
| $\overline{OE}_1$ , $\overline{OE}_2$ | 3-STATE Output Enable Inputs |
| I <sub>0</sub> –I <sub>7</sub>        | Inputs                       |
| O <sub>0</sub> -O <sub>7</sub>        | Outputs                      |

## **Logic Symbol**



## Truth Tables

| Inp<br>OE <sub>1</sub> | uts I | Outputs<br>(Pins 12, 14, 16, 18 | 3) |
|------------------------|-------|---------------------------------|----|
| L                      |       | L                               |    |
| O L                    | Н     | Н                               |    |
| H                      | Х     | Z                               |    |

| Inp             | uts | Outputs           |
|-----------------|-----|-------------------|
| OE <sub>2</sub> | In  | (Pins 3, 5, 7, 9) |
| L               | L   | L                 |
| L               | Н   | Н                 |
| Н               | X   | Z                 |

H = HIGH Voltage Level

L = LOW Voltage Level

X = Immaterial

Z = High Impedance

### **Absolute Maximum Ratings**

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

| Symbol           | Parameter   | Rating             |
|------------------|---|--------------------|
| V <sub>CC</sub>  | Supply Voltage                                      | -0.5V to +4.6V     |
| V <sub>I</sub>   | DC Input Voltage                                    | -0.5V to +7.0V     |
| Vo               | DC Output Voltage                                   |                    |
|                  | Output in 3-STATE                                   | -0.5V to +7.0V     |
|                  | Output in HIGH or LOW State <sup>(1)</sup>          | -0.5V to +7.0V     |
| I <sub>IK</sub>  | DC Input Diode Current, V <sub>I</sub> < GND        | -50mA              |
| I <sub>OK</sub>  | DC Output Diode Current, V <sub>O</sub> < GND       | -50mA              |
| Io               | DC Output Current, V <sub>O</sub> > V <sub>CC</sub> |                    |
|                  | Output at HIGH State                                | 64mA               |
|                  | Output at LOW State                                 | 128mA              |
| I <sub>CC</sub>  | DC Supply Current per Supply Pin                    | ±64mA              |
| I <sub>GND</sub> | DC Ground Current per Ground Pin                    | ±128mA             |
| T <sub>STG</sub> | Storage Temperature                                 | -65° C tc → 150° C |

#### Note:

## Recommended Operation Corditions

The Recommended Operating Continues able defines the conditions for actual device operation. Recommended operating conditions are pecified to ensure optimal performance to the detasheet specifications. Fairchild does not recommend excessing to more signing to absolute maximum ratings.

| Symb '           | Parameter  | Min. | Max. | Units |
|------------------|--|------|------|-------|
|                  | S: voltage   | 2.7  | 3.6  | V     |
| VI               | nput Voltage   | 0    | 5.5  | V     |
| I <sup>OF,</sup> | HIGH-Level Output current  |      | -12  | mA    |
| OL               | LOW-Level Output Curlent   |      | 12   | mA    |
| TA               | Free-Air Operating Temperature                                       | -40  | 85   | °C    |
| Δ*/ ΔV           | Input Edge Rate, V <sub>IN</sub> = 0.8V–2.0V, V <sub>CC</sub> = 3.0V | 0    | 10   | ns/V  |

<sup>1.</sup> In Absolute Maximum Rating must be of a ved.

#### **DC Electrical Characteristics**

|                                     |                                    |                              |                     |   | T <sub>A</sub> = -4   | l0°C to +           | 85°C       |       |
|-------------------------------------|------------------------------------|------------------------------|---------------------|---|-----------------------|---------------------|------------|-------|
| Symbol                              | Parame                             | ter                          | V <sub>CC</sub> (V) | Conditions  | Min.                  | Typ. <sup>(2)</sup> | Max.       | Units |
| V <sub>IK</sub>                     | Input Clamp Diode Voltage          |                              | 2.7                 | $I_I = -18mA$   |                       |                     | -1.2       | V     |
| V <sub>IH</sub>                     | Input HIGH Voltage                 |                              | 2.7–3.6             | $V_0 \le 0.1V$ or   | 2.0                   |                     |            | V     |
| V <sub>IL</sub>                     | Input LOW Voltage                  |                              | 2.7–3.6             | $V_{O} \ge V_{CC} - 0.1V$   |                       |                     | 0.8        | V     |
| V <sub>OH</sub>                     | Output HIGH Voltage                | )                            | 2.7–3.6             | $I_{OH} = -100\mu A$  | V <sub>CC</sub> - 0.2 |                     |            | V     |
|                                     |                                    |                              | 3.0                 | I <sub>OH</sub> = -12mA   | 2.0                   |                     |            |       |
| $V_{OL}$                            | Output LOW Voltage                 |                              | 2.7                 | $I_{OL} = 100 \mu A$  |                       |                     | 0.2        | V     |
|                                     |                                    |                              | 3.0                 | I <sub>OL</sub> = 12mA  |                       |                     | 0.8        |       |
| I <sub>I(HOLD)</sub> <sup>(3)</sup> | Bushold Input Minima               | um Drive                     | 3.0                 | V <sub>I</sub> = 0.8V   | 75                    |                     |            | μA    |
|                                     |                                    |                              |                     | V <sub>I</sub> = 2.0V   | -75                   |                     |            | 15    |
| I <sub>I(OD)</sub> (3)              | Bushold Input Over-D               | rive Current to              | 3.0                 | (4)   | 5                     |                     |            | μA    |
|                                     | Change State                       |                              |                     | (5)   | 50∟                   |                     | N          | ĺ     |
| I <sub>I</sub>                      | Input Current                      |                              | 3.6                 | V <sub>I</sub> = 5.5V   |                       |                     | 10         | μA    |
|                                     |                                    | Control Pins                 | 3.6                 | V <sub>I</sub> = 0V or V <sub>CC</sub>                                      |                       | 160                 | ±1         |       |
|                                     |                                    | Data Pins                    | 3.6                 | V <sub>I</sub> ¬V   |                       |                     | <b>-</b> 5 |       |
|                                     |                                    |                              |                     | √ <sub>I</sub> = \  | . 60                  |                     | 1          |       |
| I <sub>OFF</sub>                    | Power Off Leakage C                | Current                      | C                   | $V \le V_1$ $V_0 \le 5.5$   | ) ' 0                 | 5                   | ±100       | μA    |
| I <sub>PU/PD</sub>                  | Power up/down 3-ST. Output Current | ATE                          | L 1.5               | V = 0.5V  to  (0.0V)<br>$V_I = GND > V_{CC}$                                | 20                    | MP                  | ±100       | μA    |
| I <sub>OZL</sub>                    | 3-STATE Output Leal                | kage un t                    | 3.6                 | $V_{\rm O} = 0.5V$  |                       |                     | <b>-</b> 5 | μA    |
| I <sub>OZH</sub>                    | 3-STATE Output Leal                | ka Curren                    | 3.6                 | V <sub>C</sub> = 3.0V   | TIP O                 |                     | 5          | μA    |
| I <sub>OZH</sub> +                  | 3-STATE Outr                       | kag. Turrer                  | 3.6                 | $V_{CC} < V_O \le 5.5V$   |                       |                     | 10         | μA    |
| I <sub>CCH</sub>                    | Power Suppl Currer                 | nt                           | 3.3                 | Outouts HIG'i   |                       |                     | 0.19       | mA    |
| I <sub>CCL</sub>                    | Pov Supply rer                     | 7                            | 3.6                 | Outputs LOW   |                       |                     | 5          | mA    |
| I <sub>CCZ</sub>                    | Pow app. Current                   |                              | 3.5                 | Ou pats Disabled  |                       |                     | 0.19       | mA    |
|                                     | ver y Curre                        | CK                           | 3.6                 | $V_{CC} \le V_O \le 5.5V$ ,<br>Outputs Disabled                             |                       |                     | 0.19       | mA    |
| 'cc                                 | ncrease in Power Su                | ipply Current <sup>(6)</sup> | 3.6                 | One Input at V <sub>CC</sub> – 0.6V, Other Inputs at V <sub>CC</sub> or GND |                       |                     | 0.2        | mA    |

#### Notes:

- 2. All typical values are at  $V_{CC} = 3.3V$ ,  $T_A = 25$ °C.
- 3 Applies to bushold versions only (74LVTH2244).
- 4. An external driver must source at least the specified current to switch from LOW-to-HIGH.
- 5. An external driver must sink at least the specified current to switch from HIGH-to-LOW.
- 6. This is the increase in supply current for each, input that is at the specified voltage level rather than  $V_{CC}$  or GND.

## Dynamic Switching Characteristics<sup>(7)</sup>

|                  |   |                     | Conditions                      | Т    | A = 25° | С    |       |
|------------------|---|---------------------|---------------------------------|------|---------|------|-------|
| Symbol           | Parameter                                       | V <sub>CC</sub> (V) | $C_L = 50 pF, R_L = 500 \Omega$ | Min. | Тур.    | Max. | Units |
| V <sub>OLP</sub> | Quiet Output Maximum<br>Dynamic V <sub>OL</sub> | 3.3                 | (8)                             |      | 0.8     |      | V     |
| V <sub>OLV</sub> | Quiet Output Minimum<br>Dynamic V <sub>OL</sub> | 3.3                 | (8)                             |      | -0.8    |      | V     |

#### Notes:

- 7. Characterized in SOIC package. Guaranteed parameter, but not tested.
- 8. Max number of outputs defined as (n). n-1 data inputs are driven 0V to 3V. Output under test held LOW.

#### **AC Electrical Characteristics**

|                  |                                  |      | T <sub>A</sub> = · | –4′`C | ა°C,<br>50′       | N    |       |
|------------------|----------------------------------|------|--------------------|-------|-------------------|------|-------|
|                  |                                  | Vcc  | = (3V.             | 7.3V  | V <sub>CC</sub> - | 2.7V |       |
| Symbol           | Parameter                        | Min. | TVL (9)            | ٠٨.   | Min.              | Max. | Units |
| t <sub>PLH</sub> | Propagation Delay Data to Output | 77   |                    | 4.4   | 1.0               | 5.3  | ns    |
| t <sub>PHL</sub> |                                  | 1.0  |                    | 4.1   | 1.0               | 4.4  |       |
| t <sub>PZH</sub> | Output Enable Time               | 1.0  |                    | 5.9   | 1.0               | 7.7  | ns    |
| t <sub>PZL</sub> |                                  | 7.1  | ND.                | ?).5  | 1.1               | 6.2  |       |
| t <sub>PHZ</sub> | Output Disable Time              | 1.9  |                    | 6.1   | 1.9               | 6.8  | ns    |
| t <sub>PLZ</sub> |                                  | 1.8  | 1                  | 11.5  | 1.8               | 4.5  |       |
| toshl, toslh     | Output to are at S. (10)         |      |                    | 1.0   |                   | 1.0  | ns    |

#### Notes:

- 9. All typical values are  $\sim 3.3 \text{V}$  T<sub>A</sub> = 25°C.
- 10. Skew de. as absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, or the same direction, or LOW-to-HIGH (toolh).

## Cap Litange (11)

| Symbol           | Pararieter         | Conditions                                 | Typical | Units |
|------------------|--------------------|--|---------|-------|
| C <sub>IN</sub>  | Input Capacitance  | $V_{CC} = 0V$ , $V_I = 0V$ or $V_{CC}$     | 3       | pF    |
| C <sub>OUT</sub> | Output Capacitance | $V_{CC} = 3.0V$ , $V_{O} = 0V$ or $V_{CC}$ | 6       | pF    |

#### Note:

11. Capacitance is measured at frequency f = 1MHz, per MIL-STD-883B, Method 3012.

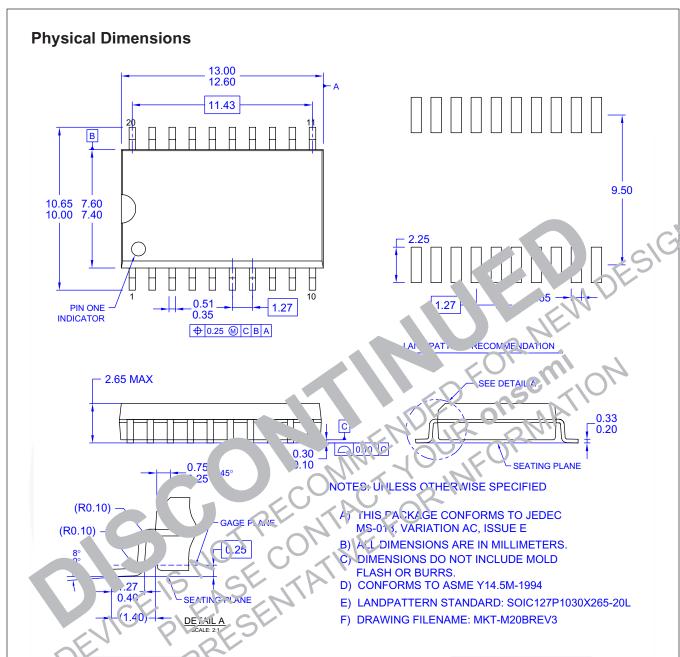


Figure 1. 20-Levi Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide

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## Physical Dimensions (Continued) 12.6±0.10 0.40 TYP -A-20 11 12 5.01 TYP 5.3±0.10 9.27 TYP 7.8 -B-3.9 △ 0.2 C B A ALL LEAD TIPS 10 PIN #1 IDENT. J.6 TYP 1.27 ALL LEAD TIPS △ 0.1 C 2.1 MAX. -C-0.15 - 0.255.35-0.51 1.27 TYP 7° TYP ARE IN MULIMETER GAGE PLANE 0°-8° TYP CONFORMS TO LIAU EDG-7320 REGISTRATION ESTABLISHED IN DECEMBER, 1998. D.Y.LNSIONS ARE EXCLUSIVE (% 10.4RS, MOLD FLASH, AND TIE BAR EXTRUSIONS. $0.60 \pm 0.15$ SEATING PLANE 1.25 -DETAIL A

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Figure 2. 20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide

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M20DREVC

## Physical Dimensions (Continued) 5.5±0.1 -A--0.20 وحا 4.16 6,4 4.4±0.1 -B-3,2 0.65 ALL LEAD PIN #1 IDENT. O.1 C -0.90 1.2 -C-0.09-0.20 0.05 0.65 -<u>().</u> 1<u>00</u>0 | A| B(S) (S) -12.00° GAGE PLANE 0.25 SEATING PLANE CONFORMS TO JEDEC RESISTRATION MIL-133 REF NOTE 6, DATE 7/33. VARIATION AC, -0.6±0.1 R0.09min D'MENSIONS ARE IN MILLIMETERS. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLDS FLASH, AND TIE BAR EXTRUSIO IS

MTC20REVD1

D. DIMENSIONS AND TO ERANCES PER ANSI Y14.5M, 1982.

#### Figure 3. 20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

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DETAIL A



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Rev. 133

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